TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRANSISTOR

TLP285

Power Supplies Programmable Controllers Hybrid ICs

The Toshiba TLP285 consists of photo transistor, optically coupled to a gallium arsenide infrared emitting diode. TLP285 is housed in the SOP4 package, very small and thin coupler.

Since TLP285 is guaranteed wide operating temperature (Ta=-55 to 110 $^{\circ}$ C) and high isolation voltage (3750Vrms), it's suitable for high-density surface mounting applications such as small switching power supplies and programmable controllers.

Collector-Emitter Voltage : 80 V (min)
 Current Transfer Ratio : 50% (min)
 Rank GB : 100% (min)
 Isolation Voltage : 3750 Vrms (min)
 Guaranteed performance over -55 to 110 °C

UL Recognized : UL1577 , File No. E67349

cUL Recognized : CSA Component Acceptance Service

No.5A

BSI Approved : BS EN 60065: 2002,

: BS EN 60950-1: 2006

Option (V4)

VDE approved : EN60747-5-2

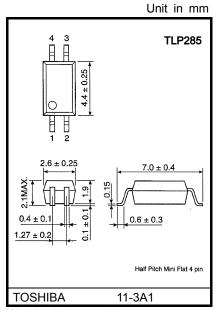
Maximum operating insulation voltage : 707 Vpk

Highest permissible over-voltage : 6000 Vpk

(Note) When a EN60747-5-2 approved type is needed, please designate the "Option(V4)"

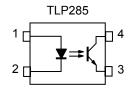
Construction Mechanical Rating

Creepage Distance	5.0 mm (min)
Clearance	5.0 mm (min)
Insulation Thickness	0.4 mm (min)



Weight: 0.05 g (typ.)

Pin Configuration



1:ANODE 2:CATHODE 3:EMITTER 4:COLLECTOR

Current Transfer Ratio

TVDE	Classification			M 1: 60 : 6 : 6
TYPE	(Note1)	I _F = 5 mA, V _{CE} = 5 V, Ta = 25°C		Marking of Classification
		Min	Max	
	Blank	50	600	Blank ,Y [■] ,YE,G,G [■] ,GR,B,BL,GB
	Rank Y	50	150	YE
	Rank GR	100	300	GR
	Rank BL	200	600	BL
TLP285	Rank GB	100	600	GB
	Rank YH	75	150	Y =
	Rank GRL	100	200	G
	Rank GRH	150	300	G [®]
	Rank BLL	200	400	В

Note1: Ex. rank GB: TLP285 (GB)

Application type name for certification test, please use standard product type name, i.e.

TLP285 (GB): TLP285

Absolute Maximum Ratings (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
	Forward Current	I _{F(RMS)}	50	mA
	Forward Current Derating	Δl _F /°C	−1.0 (Ta≥75°C)	mA /°C
LED	Pulse Forward Current (Note2)	I _{FP}	1	Α
	Reverse Voltage	V _R	5	V
	Junction Temperature	Tj	125	°C
	Collector-Emitter Voltage	V _{CEO}	80	V
~	Emitter-Collector Voltage	V _{ECO}	7	V
DETECTOR	Collector Current	IC	50	mA
TEC	Collector Power Dissipation	PC	150	mW
DE	Collector Power Dissipation Derating(Ta≥25°C)	ΔP _C /°C	-1.5	mW /°C
	Junction Temperature	Tj	125	°C
Operating Temperature Range		T _{opr}	−55 to 110	°C
Storage Temperature Range		T _{stg}	−55 to 125	°C
Lead Soldering Temperature		T _{sol}	260 (10s)	°C
Total Package Power Dissipation		P _T	200	mW
	al Package Power Dissipation ating (Ta≥25°C)	ΔP _T /°C	-2.0	mW /°C
Isola	ation Voltage (Note3)	BVS	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note2 : Pulse width ≤ 100µs, frequency 100Hz

Note3 : AC, 1 minute, R.H.≤60%, Device considered a two terminal device : LED side pins shorted together and DETECTOR side pins shorted together.

Individual Electrical Characteristics (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
	Forward Voltage	V_{F}	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I _R	V _R = 5 V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	_	pF
	Collector-Emitter Breakdown Voltage	V _(BR) CEO	I _C = 0.5 mA	80	_	_	V
	Emitter-Collector Breakdown Voltage	V _{(BR) ECO}	I _E = 0.1 mA	7	_	_	٧
DETECTOR	Collector Dark Current (Note5)	loso	V _{CE} = 48 V, Ambient Light Below (100 (x) (Note 4)	_	0.01 (2)	0.1 (10)	μΑ
DET	(Notes)	ICEO	V _{CE} = 48 V, Ta = 85°C Ambient Light Below (100 &x) (Note 4)	_	2 (4)	50 (50)	μΑ
	Capacitance (Collector to Emitter)	C _{CE}	V = 0, f = 1 MHz	_	10	_	pF

Note.4: Irradiation to marking side using standard light bulb.

Note 5 :Because of the construction, leak current might be increased by ambient light.

Please use photocoupler with less ambient light.

Coupled Electrical Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Current Transfer Ratio	I _C / I _F	I _F = 5 mA, V _{CE} = 5 V	50	_	600	%
Current Transier Natio	IC / IF	Rank GB	100	_	600	/0
Saturated CTR	lo/le/ o	I _F = 1 mA, V _{CE} = 0.4 V	_	60	_	%
Salurated CTK	I _C / I _{F (sat)}	Rank GB	30	_	_	/0
Collector-Emitter		I _C = 2.4 mA, I _F = 8 mA	_	_	0.4	
Saturation Voltage	V _{CE} (sat)	I _C = 0.2 mA, I _F = 1 mA	_	0.2	_	V
Cataration voltage		Rank GB	_	_	0.4	
OFF-State Collector Current	I _{C (off)}	V _F = 0.7 V, V _{CE} = 48 V	1	_	10	μA

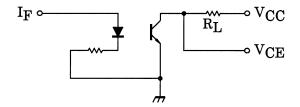
Isolation Characteristics (Ta = 25°C)

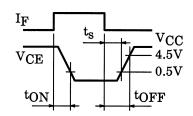
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Capacitance (Input to Output)	CS	V _S = 0 V, f = 1 MHz		0.8	1	pF
Isolation Resistance	R_S	V _S = 500 V, R.H.≤60%	1×10 ¹²	10 ¹⁴	1	Ω
		AC , 1 minute	3750	-	_	Vrms
Isolation Voltage	BV_S	AC , 1 second, in OIL	_	10000	_	VIIIIS
		DC , 1 minute, in OIL	_	10000	_	Vdc

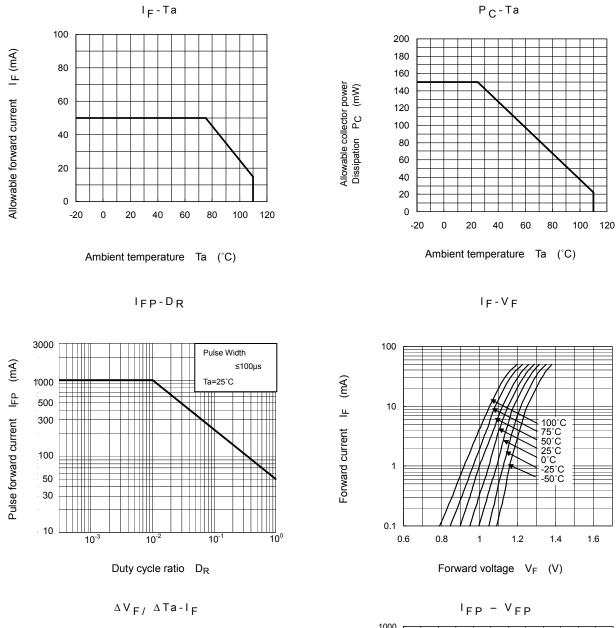
Switching Characteristics (Ta = 25°C)

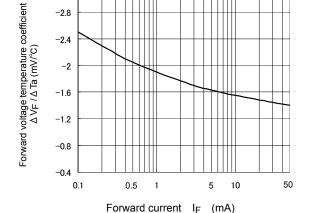
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Rise Time	t _r		_	2	_	
Fall Time	t _f	$V_{CC} = 10 \text{ V}, I_{C} = 2 \text{ mA}$	_	3	_	μs
Turn-On Time	t _{on}	R _L = 100Ω	ı	3	_	μδ
Turn-Off Time	t _{off}		-	3	_	
Turn-On Time	ton		ı	2	_	
Storage Time	ts	$R_L = 1.9 \text{ k}\Omega$ (Fig.1) $V_{CC} = 5 \text{ V}, I_F = 16 \text{ mA}$	-	25	_	μs
Turn-Off Time	t _{OFF}		_	40	_	

(Fig.1) Switching Time Test Circuit









-3.2

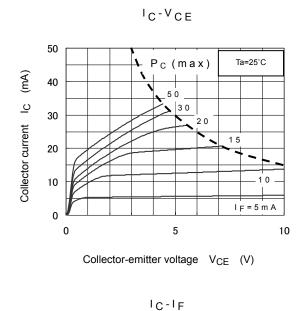
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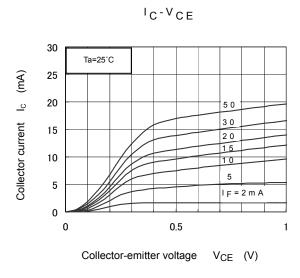
1000 (mA) FP 100 Pulse forward current 10 Pulse width≤10µs Frequency=100Hz Ta=25°C 0.6 1 1.4 1.8 2.2 2.6 3

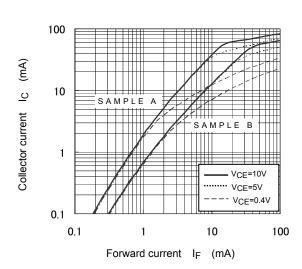
Pulse forward voltage VFP (V)

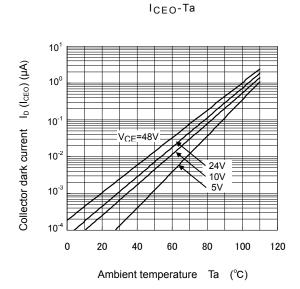
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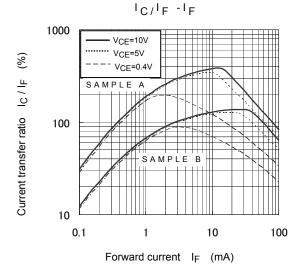
^{*}The above graphs show typical characteristic.





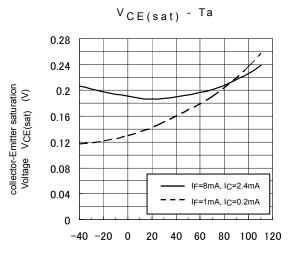




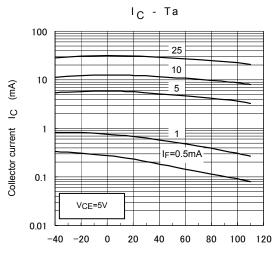


^{*}The above graphs show typical characteristic.

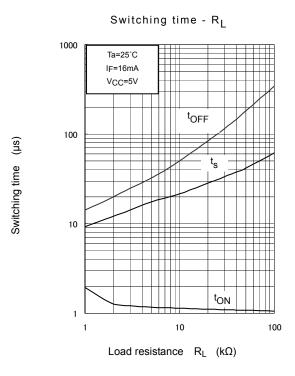
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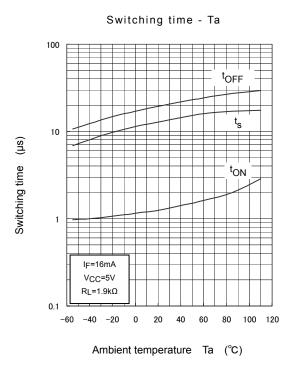






Ambient temperature Ta (°C)





^{*}The above graphs show typical characteristic.

Soldering and Storage

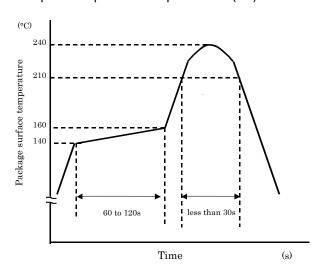
1. Soldering

1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as much as possible by observing the following conditions.

1) Using solder reflow

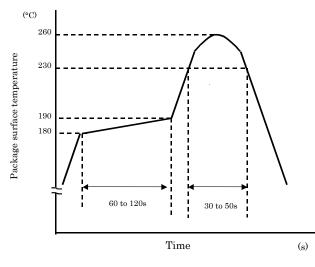
·Temperature profile example of lead (Pb) solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

·Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

- 2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)
 - Please preheat it at 150°C between 60 and 120 seconds.
 - · Complete soldering within 10 seconds below 260°C. Each pin may be heated at most once.
- 3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.

2. Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

Option :Specification for Embossed-Tape Packing (TP) for Mini-Flat Coupler

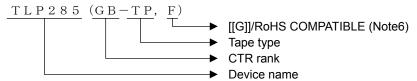
1. Applicable Package

Package	Product Type
SOP4	Mini-Flat Coupler

2. Product Naming System

Type of package used for shipment is denoted by a symbol suffix after a product number. The method of classification is as below.

(Example)



3. Tape Dimensions

3.1 Orientation of Device in Relation to Direction of Tape Movement

Device orientation in the recesses is as shown in Figure 1.

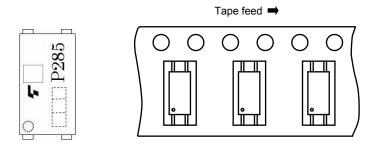


Figure 1 Device Orientation

3.2 Tape Packing Quantity: 2500 devices per reel

3.3 Empty Device Recesses Are as Shown in Table 1.

Table 1 Empty Device Recesses

	Standard	Remarks	
Occurrences of 2 or more successive empty device recesses	0	Within any given 40-mm section of tape, not including leader and trailer	
Single empty device recesses	6 device (max.) per reel	Not including leader and trailer	

3.4 Start and End of Tape

The start of the tape has 50 or more empty holes. The end of tape has 50 or more empty holes and two empty turns only for a cover tape.

3.5 Tape Specification

- (1) Tape material: Plastic (protection against electrostatics)
- (2) Dimensions: The tape dimensions are as shown in Figure 2 and table 2.

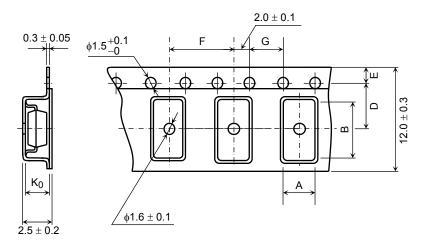


Figure 2 Tape Forms

Table 2 Tape Dimensions

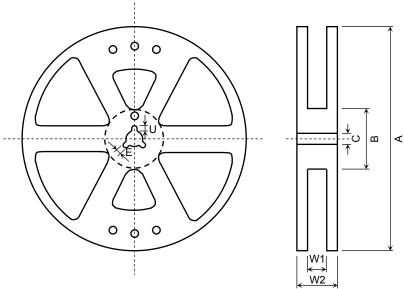
Unit: mm Unless otherwise specified: ±0.1

Symbol	Dimension	Remark
А	3.1	-
В	7.5	_
D	5.5	Center line of indented square hole and sprocket hole
Е	1.75	Distance between tape edge and hole center
F	8.0	Cumulative error +0.1 (max.) per 10 feed holes
G	4.0	Cumulative error +0.1 (max.) per 10 feed holes
Κ ₀	2.3	Internal space



3.6 Reel

- (1) Material: Plastic
- (2) Dimensions: The reel dimensions are as shown in Figure 3 and Table 3.



Unit: mm Symbol Dimension Ф330 ±2 В Φ80 ±1 С Φ13 ±0.5 Ε 2.0 ±0.5 U 4.0 ±0.5 W1 13.5 ±0.5 W2 17.5 ±1.0

Table3 Reel Dimensions

TLP285

Fi-----

Figure 3 Reel Form

4. Packing

Either one reel or ten reels of photocoupler are packed in a shipping carton.

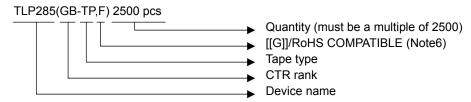
5. Label Indication

The carton bears a label indicating the product number, the symbol representing classification of standard, the quantity, the lot number and the Toshiba company name.

6. Ordering Method

When placing an order, please specify the product number, the CTR rank, the tape type and the quantity as shown in the following example.

(Example)



Note6 : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

TOSHIBA Photocoupler

Option:(V4)

Attachment : Specifications for <u>EN60747-5-2</u> option: (V4)

Types : TLP285(F)

Type designations for "option: (V4)", which are tested under EN60747 requirements.

Ex.: TLP285 (V4-GB-TP,F) $\qquad \qquad \text{V4}: EN60747 \ \text{option}$

GB: CTR rank type

TP: Standard tape & reel type

F : [[G]]/RoHS COMPATIBLE (Note 6)

Note: Use TOSHIBA standard type number for safety standard application.

Ex.: TLP285 (V4-GB-TP,F) \rightarrow TLP285

EN60747 Isolation Characteristics

Description	Symbol	Rating	Unit
Application classification for rated mains voltage ≤ 150Vrms for rated mains voltage ≤ 300Vrms		I-IV I-III	_
Climatic classification		55 / 110 / 21	_
Pollution degree		2	_
Maximum operating insulation voltage	VIORM	707	Vpk
Input to output test voltage, Method A Vpr=1.5 × V _{IORM} , type and sample test tp=10s, partial discharge<5pC	V _{pr}	1060	Vpk
Input to output test voltage, Method B Vpr=1.875 × V _{IORM} , 100% production test tp=1s, partial discharge<5pC	V _{pr}	1325	Vpk
Highest permissible overvoltage (transient overvoltage, tpr=60s)	V _{TR}	6000	Vpk
Safety limiting values (max. permissible ratings in case of fault, also refer to thermal derating curve) current (input current I _F , Psi=0) power (output or total power dissipation) temperature Insulation resistance V _{IO} =500V, Ta=T _{si}	I _{Si} P _{Si} T _{Si}	250 400 150 ≥ 10 ⁹	mA mW °C

Insulation Related Specifications

Minimum creepage distance	Cr	5.0mm
Minimum clearance	CI	5.0mm
Minimum insulation thickness	ti	0.4mm
Comparative tracking index	CTI	175

 If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. (e.g. at a standard distance between soldering eye centers of 3.5mm).
 If this is not permissible, the user shall take suitable measures.

2. This photocoupler is suitable for 'safe electrical isolation' only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuit.

VDE test sign: Marking on product

for EN60747

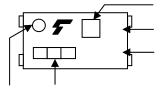
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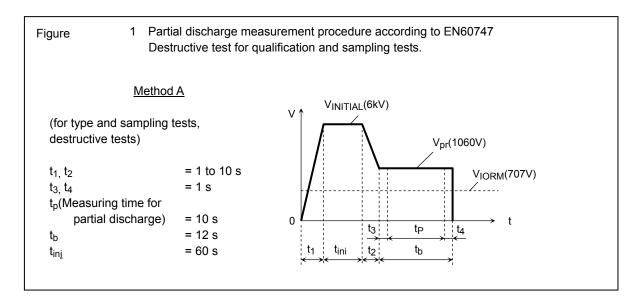
: Marking on packing for EN60747

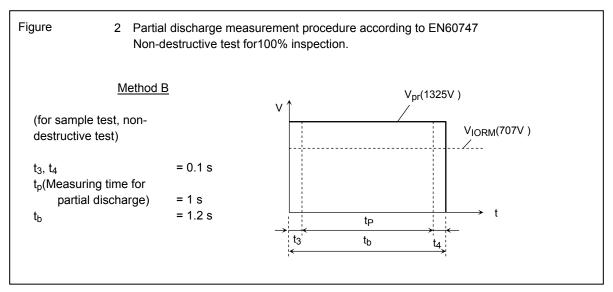


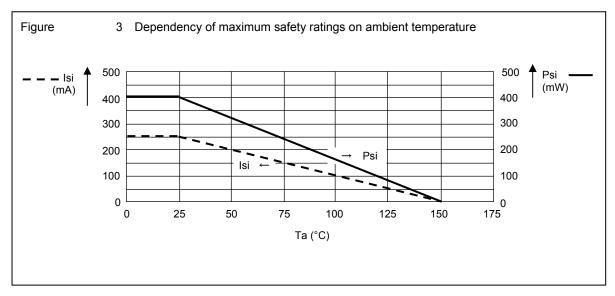
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Marking Example: TLP285(F)









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